

INVENTOR INFORMATION

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CORRESPONDENCE INFORMATION

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APPLICATION INFORMATION

Title Line One:: CRYSTALLINE SEMICONDUCTOR THIN FILM, MET
Title Line Two:: HOD OF FABRICATING THE SAME, SEMICONDUCT
Title Line Three:: OR DEVICE AND METHOD OF FABRICATING THE
Title Line Four:: SAME
Total Drawing Sheets:: 9
Formal Drawings?:: Yes
Application Type:: Utility
Docket Number:: 740756-2330
Secrecy Order in Parent Appl.?:: No

REPRESENTATIVE INFORMATION

FOI b2 b7D b7E

Representative Customer Number:: 22204
Registration Number One:: 38285
Registration Number Two:: 35483
Registration Number Three:: 45285
Registration Number Four:: 26477
Registration Number Five:: 27997

CONTINUITY INFORMATION

This application is a:: DIVISION OF
> Application One:: 09/352,198
Filing Date:: 07-13-1999

PRIOR FOREIGN APPLICATIONS

Foreign Application One:: 10-203205
Filing Date:: 07-17-1998
Country:: Japan
Priority Claimed:: Yes
Foreign Application Two:: 11-135055
Filing Date:: 05-14-1999
Country:: Japan
Priority Claimed:: Yes

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